

TKC-TG3 Series Three-phase Open Loop Mode Hall Effect Current Sensor



TKC-TG3 series current sensor is an open loop device based on the principle of the hall effect, with a galvanic isolation between primary and secondary circuit, it provides accurate electronic measurement of three phase DC, AC or pulsed currents.

Electrical data (Ta=25°C±5°C , RL=2.0KΩ,CL=10000PF)

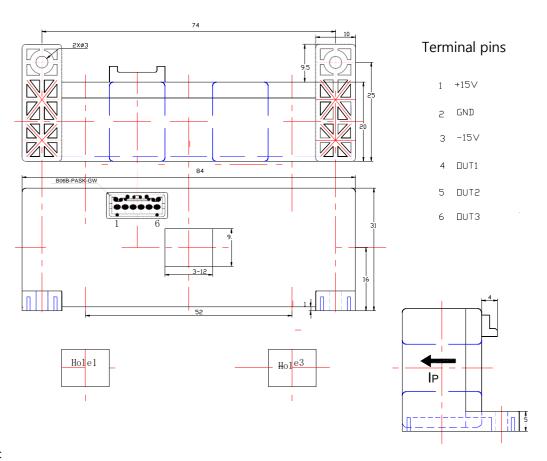
Type Parameter	ткС50ТG3	TKC100TG3	TKC150TG3	ТКС200TG3	Unit
Rated input (lpn)	±50	±100	±150	±200	А
Measure range(Ip)	±150	±300	±450	±600	А
Rated output	@lp=±lpn ±4±1.5%				
Supply voltage	±15 ±5%				
Consumption current	≤60				
Offset voltage	@Ip=0 ≤30				
Magnetic offset	@lp=±lpn-0 ≤±30				
Offset drift	≤±2.0				
Amplitude drift	0.08				
Linearity	@lp=0-±lpn ≤1				%FS
Response time	@50A/μS, 10%-90% ≤5				
Band- width	@-3dB DC-25				KHz
Galvanic isolation	@ 50HZ/60Hz,AC,1min 2.5				
Isolation resistance	@ DC 500V 500				ΜΩ

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Applications

- Variable speed drives
- Welding machine
- Battery supplied applications
- Uninterruptible Power Supplies (UPS)
- Electrochemical

Mechanical dimension (for reference only)



Remarks:

- 1. All dimensions are in mm.
- 2. General tolerance ±1mm

Directions for use

- 1. It will be in a forward direction when the Ip flows according to the direction of the arrowhead.
- 2. The primary conductor should be≤120°C.
- 3. The dynamic performance (di/dt and the response time) is the best when the primary hole is fully filled with the bus bar.
- 4. When the current will be measured goes through a sensor, the voltage will be measured at the output end. (Note: The false wiring may result in the damage of the sensor)



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- 5. Customs can adjust Output amplitude of the sensor by needs.
- 6. Custom design in the different rated input current and the output voltage are available.

Standards

UL94-V0.

EN60947-1:2004

IEC60950-1:2001

EN50178:1998

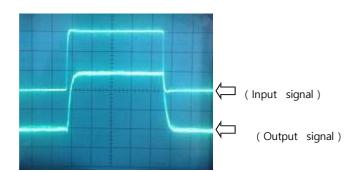
SJ 20790-2000

General data

	Value	Unit	Symbol
Operating temperature	-40 ~ +105	°C	TA
Storage temperature	-40 ~ +125	°C	TS
Mass(approx)	99	q	M

Characteristics chart

Pulse current signal response characteristic



Effects of impulse noise

